

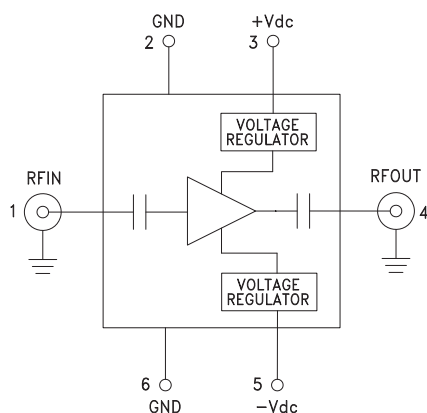


Typical Applications

The HMC-C059 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Industrial Sensors

Functional Diagram



Features

- Noise Figure: 1.8 dB @ 8 GHz
- High Gain: 16 dB @ 8 GHz
- P1dB Output Power: +16 dBm @ 8 GHz
- Spurious-Free Operation
- Regulated Supply and Bias Sequencing
- Hermetically Sealed Module
- Field Replaceable SMA connectors
- 55 to +85°C Operating Temperature

General Description

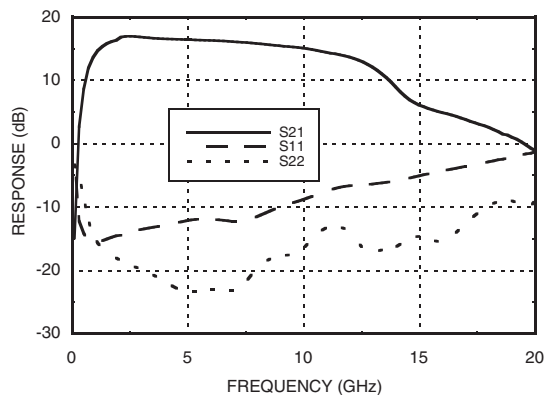
The HMC-C059 is a GaAs MMIC PHEMT Low Noise Distributed Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 1 and 12 GHz. The amplifier provides 16 dB of gain, 1.8 dB noise figure, and up to +17 dBm of output power at 1 dB gain compression. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $+V_{dc} = +6\text{V}$, $-V_{dc} = -5\text{V}$

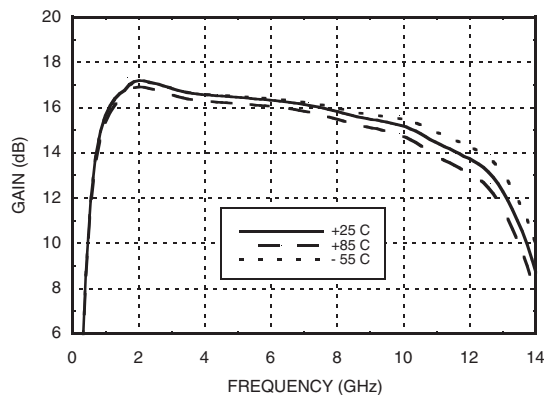
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		1 - 8		8 - 12			GHz
Gain	14	16		12	14		dB
Gain Flatness		± 1			± 1.25		dB
Gain Variation Over Temperature		0.005			0.005		dB/°C
Noise Figure		1.75	2.25		2.5	3	dB
Input Return Loss		-12			-7		dB
Output Return Loss		-17			-15		dB
Output Power for 1 dB Compression (P1dB)		17			14		dBm
Saturated Output Power (Psat)		19			17		dBm
Output Third Order Intercept (IP3)		31			29		dBm
Positive Supply Current (+IDC)		60	70		60	70	mA
Negative Supply Current (-IDC)		1.5			1.5		mA



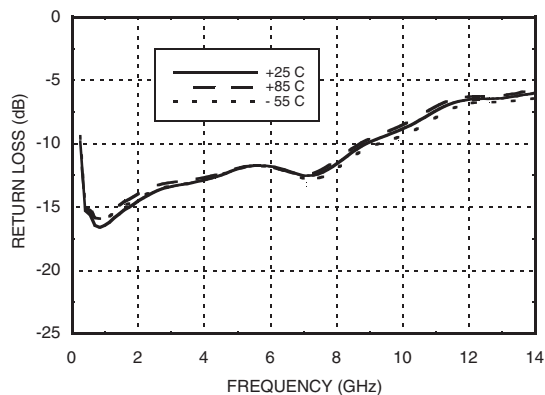
Broadband Gain & Return Loss



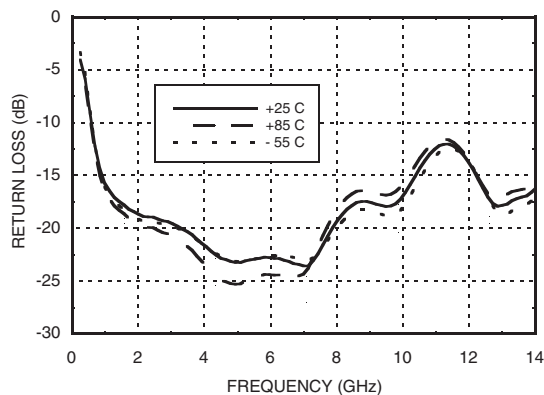
Gain vs. Temperature



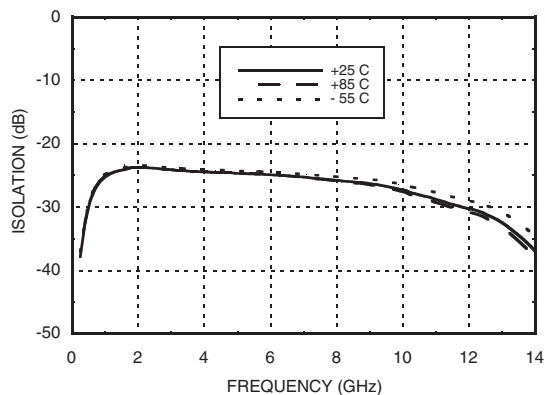
Input Return Loss vs. Temperature



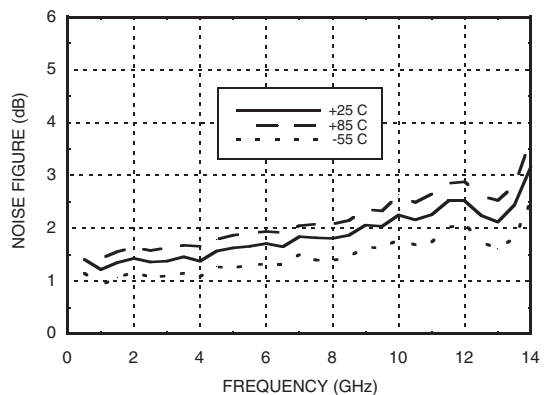
Output Return Loss vs. Temperature

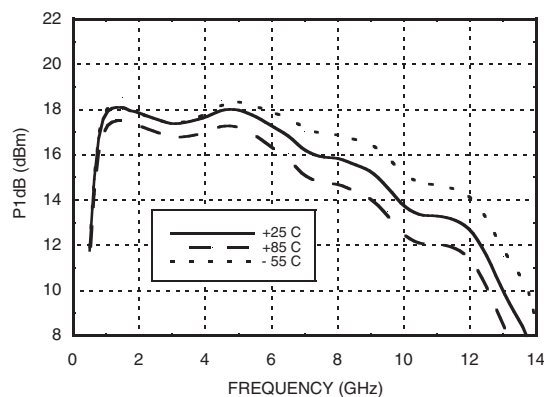
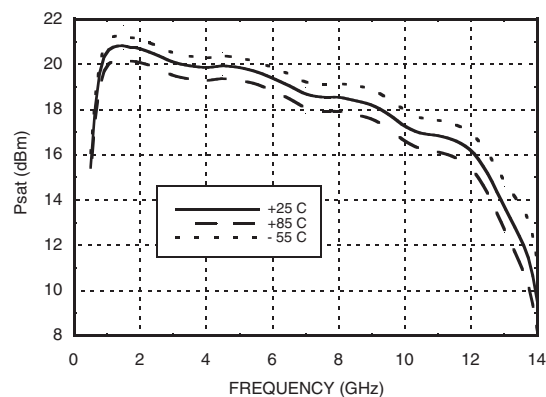
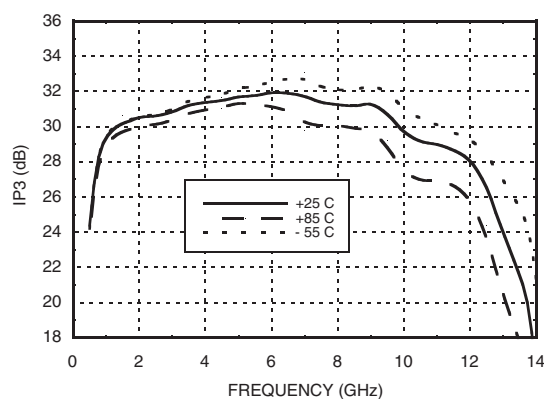


Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



P1dB vs. Temperature

Psat vs. Temperature

Output IP3 vs. Temperature

Absolute Maximum Ratings

Positive Bias Supply Voltage (+Vdc)	+16V
Negative Bias Supply (-Vdc)	-12V
RF Input Power (RFIN)	+10 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



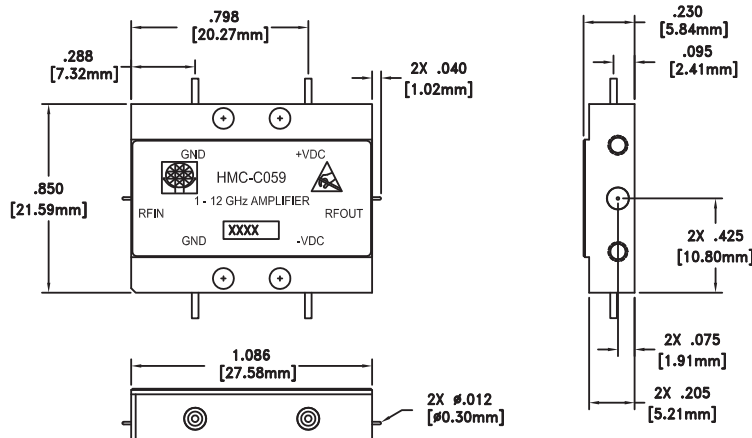
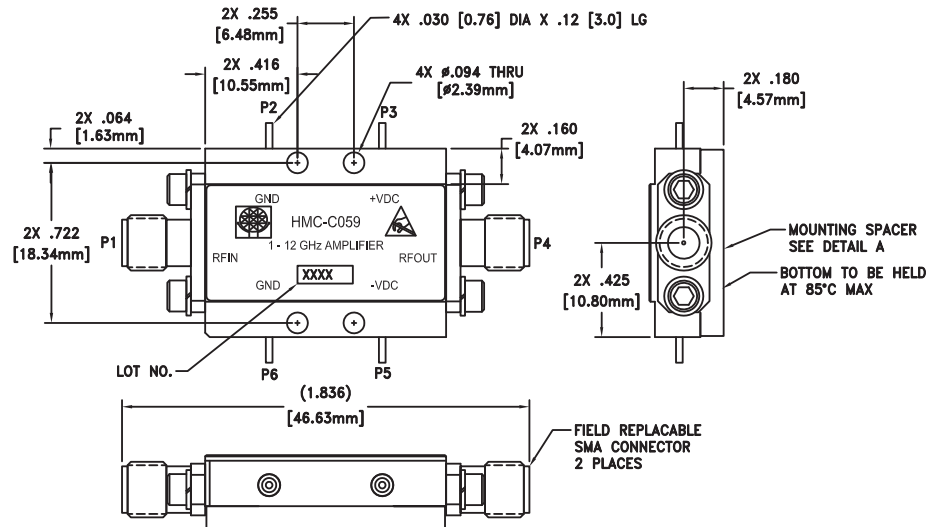
**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Pin Descriptions

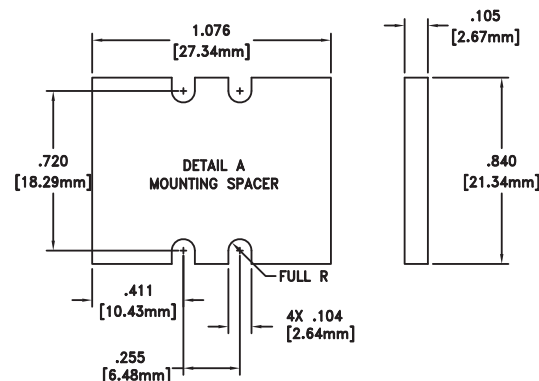
Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
2, 6	GND	Power supply ground.	
3	+Vdc	Positive power supply voltage for the amplifier.	
4	RFOUT & RF Ground	RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms.	
5	-Vdc	Negative power supply voltage for the amplifier	



Outline Drawing



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED



Package Information

Package Type	C-10B
Package Weight ^[1]	18.7 gms ^[2]
Spacer Weight	3.3 gms ^[2]

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
2. SPACER MATERIAL: ALUMINUM
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
6. FIELD REPLACEABLE SMA CONNECTORS.

⚠ TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 - 80 HARDWARE WITH DESIRED MOUNTING SCREWS.



Notes: